

# SILICON TRANSISTOR ARRAY

# $\mu$ PA1428A

## NPN SILICON POWER TRANSISTOR ARRAY HIGH SPEED SWITCHING USE (DARLINGTON TRANSISTOR) INDUSTRIAL USE

#### **DESCRIPTION**

The  $\mu$ PA1428A is NPN silicon epitaxial Darlington Power Transistor Array that built in Surge Absorber 4 circuits designed for driving solenoid, relay, lamp and so on.

#### **FEATURES**

- Surge Absorber built in.
- · Easy mount by 0.1 inch of terminal interval.
- High hee for Darlington Transistor.

#### ORDERING INFORMATION

Part Number	Package	Quality Grade		
μ <b>PA1428A</b> H	10 Pin SIP	Standard		

Please refer to "Quality grade on NEC Semiconductor Device" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

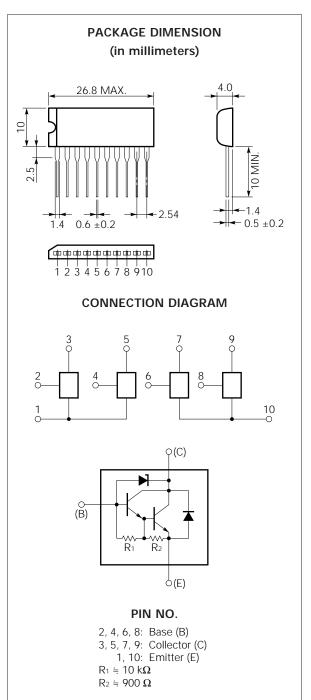
#### ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

Collector to Base Voltage	Vсво	60 ±10	V
Collector to Emitter Voltage	$V_{\text{CEO}}$	60 ±10	V
Emitter to Base Voltage	$V_{EBO}$	8	V
Surge Sustaining Energy	Eceo(sus)	30	mJ/unit
Collector Current (DC)	Ic(DC)	±2	A/unit
Collector Current (pulse)	Ic(pulse)*	±3	A/unit
Base Current (DC)	IB(DC)	0.2	A/unit
Total Power Dissipation	P <sub>T1</sub> **	3.5	W
Total Power Dissipation	P <sub>T2</sub> ***	28	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg -5	55 to +15	0 °C

\* PW  $\leq$  350  $\mu$ s, Duty Cycle  $\leq$  2 %

\*\* 4 Circuits, Ta = 25 °C

\*\*\* 4 Cuircuits, Tc = 25 °C



The information in this document is subject to change without notice.

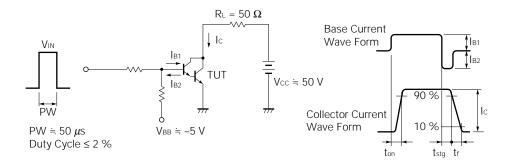


# ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Leakage Current	Ісво			1	μΑ	Vcb = 40 V, IE = 0
Emitter Leakage Current	Івво			5	mA	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0
Collector to Emitter Sustaining Voltage	VCEO(sus)	50	60	70	V	Ic = 1 A, L = 1 mH
DC Current Gain	h <sub>FE1</sub> *	2000		20000	_	Vce = 2 V, Ic = 1 A
DC Current Gain	h <sub>FE2</sub> *	500			_	Vce = 2 V, Ic = 2 A
Collector Saturation Voltage	VCE(sat) *		1.0	1.5	V	Ic = 1 A, I <sub>B</sub> = 1 mA
Base Saturation Voltage	V <sub>BE(sat)</sub> *		1.7	2	V	Ic = 1 A, I <sub>B</sub> = 1 mA
Turn On Time	ton		0.4		μs	Ic = 1 A
Storage Time	tstg		1.5		μs	$\begin{array}{l} I_{B1} = -I_{B2} = 2 \text{ mA} \\ V_{CC} \doteq 50 \text{ V}, \text{ R}_{L} = 50 \Omega \\ \text{See test circuit} \end{array}$
Fall Time	tr		0.4		μs	

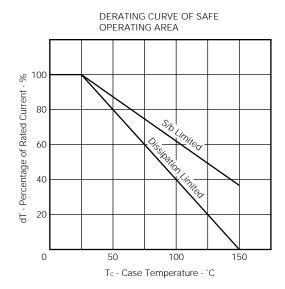
<sup>\*</sup> PW  $\leq$  350  $\mu$ s, Duty Cycle  $\leq$  2 %/pulsed

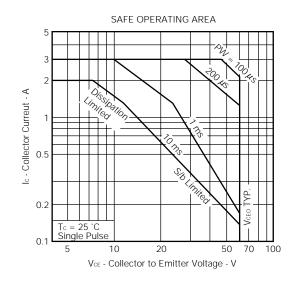
## SWITCHING TIME TEST CIRCUIT

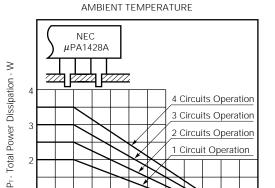




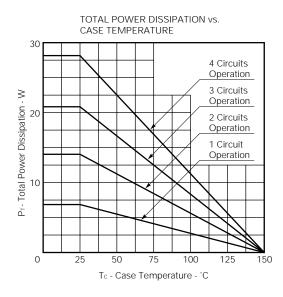
#### TYPICAL CHARACTERISTICS (Ta = 25 °C)

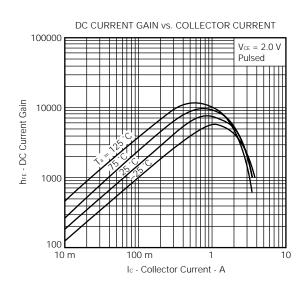




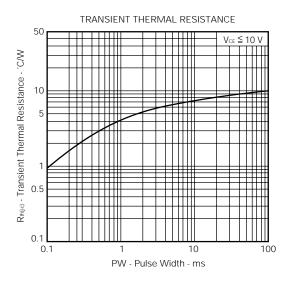


TOTAL POWER DISSIPATION vs.

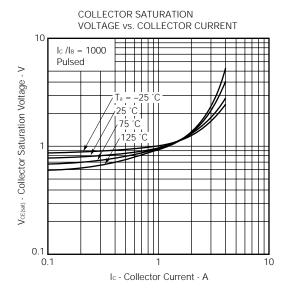


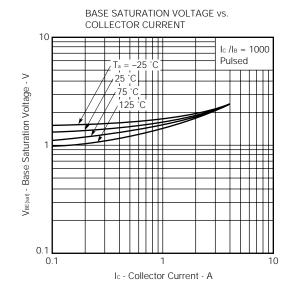


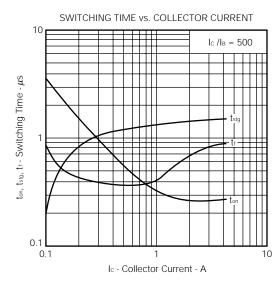
 $T_a$  - Ambient Temperature -  ${}^{\circ}C$ 

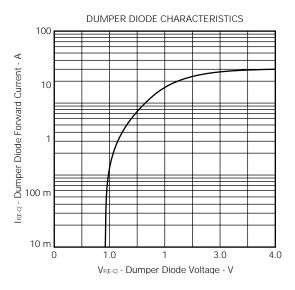














## REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134

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